Preliminary Technical Information



IXTP 8N50PM

	=	500	V
D25	=	4	Α
R _{DS(on)}	≤	0.8	Ω

PolarHV[™] **Power MOSFET** (Electrically Isolated Tab)

N-Channel Enhancement Mode Avalanche Rated



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Symbol Test Conditions		Maximum	Ratings	OVERMOLDED TO-220		
V _{dss} V _{dgr}	$T_J = 25^{\circ} C$ to $150^{\circ} C$ $T_J = 25^{\circ} C$ to $150^{\circ} C$; $R_{GS} = 1 M\Omega$	500 500	V V	(IXTPM) OUTLINE		
V _{GS} V _{GSM}	Continuous Transient	± 30 ± 40	V V			
I _{D25} I _{DM}	$T_{c} = 25^{\circ}C$ $T_{c} = 25^{\circ}C$, pulse width limited by T_{JM}	4 14	A A	G D S Isolated Tab		
I _{AR} E _{AR} E _{AS}	$T_{c} = 25^{\circ} C$ $T_{c} = 25^{\circ} C$ $T_{c} = 25^{\circ} C$	8 20 400	A mJ mJ	G = Gate D = Drain		
dv/dt	$ \begin{split} & I_{S} \leq I_{DM}, \ \text{di/dt} \leq & 100 \ \text{A/}\mu\text{s}, \ V_{DD} \leq & V_{DSS}, \\ & T_{J} \ \leq & 150^{\circ}\text{C}, \ R_{G} \ \text{=} \ 18 \ \Omega \end{split} $	10	V/ns	S = Source		
P _D	$T_c = 25^{\circ}C$	41	W			
T, T _{JM}		-55 +150 150	°C °C	Features		
T _{stg} T _L	1.6 mm (0.062 in.) from case for 10 s	-55 +150 300	2° 2°	 Plastic overmolded tab for electrical isolation International standard package 		
	Plastic body for 10 s	260	°C	 ¹ Unclamped Inductive Switching (UIS) rated 		
M _d Weight	Mounting torque	4	Nm/lb.in.	 Low package inductance easy to drive and to protect 		

Symbol (T _J = 25° C,	Test Conditions unless otherwise specified)		Ch Min.	istic Val Max	
BV _{DSS}	$V_{_{ m GS}}$ = 0 V, $I_{_{ m D}}$ = 250 μ A		500		V
V _{GS(th)}	$V_{_{DS}} = V_{_{GS}}, I_{_{D}} = 250 \mu A$		3.0	5.5	V
I _{gss}	$V_{_{\rm GS}} = \pm 30 V_{_{\rm DC}}, V_{_{\rm DS}} = 0$			±100	nA
I _{DSS}	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T _J = 125° C		5 50	μΑ μΑ
R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$	cycle d < 2 %		0.8	Ω

Pulse test, t ${\leq}300~\mu\text{s},$ duty cycle d ${\leq}~2~\%$

Advantages

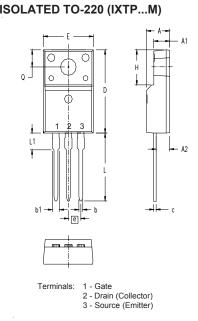
I. Easy to mount

- Т Space savings
- High power density L

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Symbol Test Conditions			Characteristic Values = 25° C, unless otherwise specified)		
		(1, 20	Min.	Typ.	Max.
g _{fs}		V _{DS} = 10 V; I _D = 4 A	5	8	S
C)			1050	pF
C _{oss}	}	$V_{GS} = 0 \text{ V}, \text{ V}_{DS} = 25 \text{ V}, \text{ f} = 1 \text{ MHz}$		120	pF
C _{rss}	J			12	pF
t _{d(on)}				22	ns
t,	ļ	$V_{_{ m GS}}$ = 10 V, $V_{_{ m DS}}$ = 0.5 $V_{_{ m DSS}}$, $I_{_{ m D}}$ = 8 A		28	ns
t _{d(off)}	(R_{g} = 18 Ω (External)		65	ns
t _f	J			23	ns
Q _{g(on)}				20	nC
Q _{gs}	}	V_{GS} = 10 V, V_{DS} = 0.5 V_{DSS} , I_{D} = 4 A		7	nC
\mathbf{Q}_{gd}	J			7	nC
$R_{_{\mathrm{thJS}}}$					3.0 °C/W



Source-Drain Diode		Characteristic Values (T ₁ = 25° C, unless otherwise specified)			
Symbol	Test Conditions	Min.	Typ.	Max.	
l _s	$V_{GS} = 0 V$			8	Α
I _{SM}	Repetitive			14	Α
V_{sd}	I _F = I _S , V _{GS} = 0 V, Pulse test, t ≤300 μs, duty cycle d≤	≤2 %		1.5	V
t _{rr}	I _F = 3 A, V _{GS} = 0 V, V _R = 100 V -di/dt = 100 A/μs		400		ns

SYM	INCH	IES	MILLIN	MILLIMETERS		
3114	MIN	MAX	MIN	MAX		
А	.177	.193	4.50	4.90		
A1	.092	.108	2.34	2.74		
A2	.101	.117	2.56	2.96		
b	.028	.035	0.70	0.90		
b1	.050	.058	1.27	1.47		
С	.018	.024	0.45	0.60		
D	.617	.633	15.67	16.07		
E	.392	.408	9.96	10.36		
е	.100	.100 BSC		2.54 BSC		
Н	.255	.271	6.48	6.88		
L	.499	.523	12.68	13.28		
L1	.119	.135	3.03	3.43		
ØР	.121	.129	3.08	3.28		
Q	.126	.134	3.20	3.40		

PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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IXYS MOSFETs and IGBTs are covered by 4,835	592 4,931,844	5,049,961	5,237,481	6,162,665	6,404,065 B1	6,683,344	6,727,585
one or moreof the following U.S. patents: 4,850	072 5,017,508	5,063,307	5,381,025	6,259,123 B1	6,534,343	6,710,405B2	6,759,692
4,881	106 5,034,796	5,187,117	5,486,715	6,306,728 B1	6,583,505	6,710,463	6,771,478 B2